Chemical solution deposition of multiferroic La$_{0.7}$Sr$_{0.3}$MnO$_3$, BaTiO$_3$ thin films prepared by ink plotting

A. Kirchner$^1$, M. Arin$^2$, P. Lommens$^2$, X. Granados$^3$, S. Ricart$^3$, B. Holzapfel$^1$, I. Van Driessche$^2$

$^1$ IFW Dresden, Institute for Metallic Materials, Helmholtzstr. 20, 01069 Dresden, Germany
$^2$ SCRIPIts, Department of Inorganic and Physical Chemistry, Ghent University, Krijgslaan 281 (S3), 9000 Ghent, Belgium
$^3$ Materials Science Institute of Barcelona, CSIC-ICMAB, Campus Universitat Autònoma de Barcelona, 08193 Bellaterra, Spain

Keywords: La$_{0.7}$Sr$_{0.3}$MnO$_3$, BaTiO$_3$, multiferroics, ink plotting

Abstract:
Ferroelectric BaTiO$_3$ (BTO) as well as ferromagnetic La$_{0.7}$Sr$_{0.3}$MnO$_3$ (LSMO) thin films were prepared by chemical solution deposition (CSD). Based on these, a multiferroic architecture stack of La$_{0.7}$Sr$_{0.3}$MnO$_3$ / BaTiO$_3$ layers was developed. Aqueous, environmentally friendly precursor solutions were formulated for both materials. These are used for ink plotting on SrTiO$_3$ (100) substrates. Films were subjected to a subsequent thermal treatment at the corresponding crystallization temperature. The structural as well as the magnetic and electric properties are presented. The Curie temperature of the ferromagnetic LSMO layer with a film thickness of only 100 nm was determined to 360 K. The magnetization curve indicates a hysteresis loop with a saturation magnetization of 280 emu/cm$^3$. The ferroelectric character of BTO films was demonstrated by polarization curves.

1. Introduction
Multiferroic systems consist of a ferroelectric and a ferromagnetic layer, where the layers are essentially elastically coupled. This allows to control the electric polarization of the ferroelectric layer by a magnetic field or to alter the magnetization of the ferromagnetic layer by an electric field. The coupling of magnetic and ferroelectric orders in a material is known as the “magnetoelectric effect” [1]. BaTiO$_3$ is a very intensively studied ferroelectric crystal [2]. The lattice constant of the tetragonal BTO crystal structure is $a_{\text{BTO}} = 3.99$ Å. La$_{0.7}$Sr$_{0.3}$MnO$_3$ is a ferromagnetic material with a lattice constant of $a = 3.87$ Å which is very close to the value of BaTiO$_3$ leading to tensile strain in LSMO films. LSMO offers the advantage that its lattice parameter can be finely tuned by the polarization of the ferroelectric BTO crystal [3, 4]. Consequently, the magnetic properties of the LSMO film can be influenced by the polarization of the BTO crystals.
Chemical Solution Deposition (CSD) in particular ink plotting is a promising process for a low cost fabrication of complicated and high end decorated patterns [5]. In this study, aqueous environmentally friendly precursor solutions of BaTiO$_3$ and La$_{0.7}$Sr$_{0.3}$MnO$_3$ were developed for the preparation of multiferroic architectures on SrTiO$_3$ substrates obtained from a complete CSD route.

2. Experimental

Solutions of Mn, La and Sr acetates were prepared independently in water being stabilised by glycine (Sr and La) and EDTA (Mn). Estochiometric amounts of the solved salts were mixed and accurately stired in order to obtain a solution 0.05M referred to Mn. The solution was adjusted with mQ water and ethanol to achieve a proportion of 90/10 of both solvents. TREG in a 5% and hexadeciltrimetilamonio bromide in 0.5 g/l was added to the previously prepared 0.05M (Mn) solution. The propereties of the solution are reported in Table 1.

<table>
<thead>
<tr>
<th>Table 1: propereties of the LSMO solution</th>
</tr>
</thead>
<tbody>
<tr>
<td>Density</td>
</tr>
<tr>
<td>Viscosity</td>
</tr>
<tr>
<td>Contact angle (LAO)</td>
</tr>
<tr>
<td>Surface tension</td>
</tr>
<tr>
<td>Colour</td>
</tr>
</tbody>
</table>

An aqueous BaTiO$_3$ precursor solution was prepared using titanium propoxide (TIP) (Fluka, ≥97.0%) as Ti$^{4+}$ source and barium acetate (Ba(OAc)$_2$) (Sigma-Aldrich,≥99.0%) as Ba$^{2+}$ source. Citric acid (CA) (Acros Organics, 99.5%), triethanolamine (TEA) (Acros Organics, 99+%), ethanolamine (EA) (Sigma-Aldrich, ≥99.0%), ethyleneglycol (EG) (Sigma-Aldrich, ≥99.5%) and ethanol (EtOH) (Absolute, Panreac) are added for stabilization. All materials were used without further purification.

First, a Ti-precursor solution was prepared by adding TEA to TIP in molar ratio of 2:1 and H$_2$O in 60:1 molar ratio to Ti$^{4+}$, to obtain a final Ti$^{4+}$ concentration of 0.57 M. The final pH of the solution was 8. A Ba$^{2+}$ precursor solution was prepared dissolving Ba(OAc)$_2$ in H$_2$O (in 1:112 molar ratio). EG and CA are added as complexing agents in a 4:4:1 molar ratio to Ba$^{2+}$. Afterwards, the pH of the solution was increased to 8.5 by adding EA. The final Ba$^{2+}$ concentration was set to be 0.33 M. To obtain a stable BaTiO$_3$ solution, stoichiometric amounts of both precursors are mixed to obtain a final concentration of 0.21M.
The viscosity of the solution was determined using a Brookfield DVE viscometer, and the surface tension was studied by the pendant drop method using an optical tensiometer (Kruss DSA 30).

Deposition of LSMO and BTO inks was carried out on SrTiO$_3$ (100) substrates by ink plotting using a “Sonoplot GIX Microplotter”. The Sonoplot ink plotter is capable of applying picoliters of fluid continuously creating features onto a surface. Ink is loaded by capillary forces into a hollow glass needle, which is attached to a piezoelectric element. At the resonant frequency of the loaded dispenser the fluid is sprayed out of a 10 or 30 µm diameter opening at the end of the needle. First, LSMO as well as BTO single layers were plotted separately on STO substrates. In a next step BTO layers were coated on top of a LSMO film. The wet films were dried and annealed in a tube furnace. LSMO films were pyrolized at temperatures between 250 and 500 °C in air and crystallized at 900 °C for 5 hours in oxygen atmosphere [6]. BTO films were pyrolized and crystallized at 500 °C and 700 °C in air [7]. Crack formation in BTO layers can be avoided by using a slow heating rate of 60 K/h. The desirable thickness of BTO layers was obtained through multiple coating and annealing processes. The phase structure of BaTiO$_3$ and La$_{0.7}$Sr$_{0.3}$MnO$_3$ thin films was characterized by X-ray diffraction. Topography and film thickness were studied by atomic force microscopy AFM DI 3100. SQUID (Superconducting Quantum Interference Design) measurements were used to investigate the magnetic properties of LSMO layers. In order to perform the electric characterization of BTO films, a capacitor stack of a LSMO layer / triple layer BTO / liquid silver contact was fabricated. Polarization measurements were performed at room temperature at 1000 Hz.

3. Results and discussions

3.1. Aqueous BaTiO$_3$ Precursor Solutions

We have prepared different aqueous BaTiO$_3$ precursor solutions by using triethanolamine (TEA), citric acid (CA) and ethyleneglycol (EG) as complexing agents to inhibit the hydrolysis of the Ti-alkoxide and Ba-acetate by the presence of water. Heating of a small volume of the solution poured into a petri dish to 60°C for 2 hours leads to stable and transparent gels. The density of the solution, i.e. 1.184 g/cm$^3$, was determined by standard pycnometry. We find a surface tension value ($\gamma$) of 41.59±0.25 mN/m as determined by the pendant drop method using the Young-Laplace approach. The viscosity of the solution was 10.9 cP.
3.2 Structure characterization of single LSMO and BTO layers

The surface morphology of the LSMO films was investigated by AFM, as shown in figure 1 a). The average grain size is up to 140 nm, as seen in the line scan of figure 1 b).

![AFM images of LSMO and BTO films](image)

**Fig. 1**: AFM measurements of a) crystallized LSMO film on a STO substrate with b) corresponding line scan and c) crystallized BTO film with d) corresponding line scan on a STO substrate prepared by ink plotting.

The value of the root mean square Rms was measured to be about 40 nm. The surface structure indicates a smooth surface, which is essential for ink plotting of BTO layers on top of the LSMO film. The LSMO layer thickness lies in the range of 60 nm up to 100 nm at the film edges. The X-ray diffraction spectrum obtained for a LSMO thin film deposited on a (100) STO oriented substrate reveals a La$_{0.7}$Sr$_{0.3}$MnO$_3$ film composition with a perovskite-type structure, presenting a (001) preferred growth direction, see figure 2.
Fig. 2: Typical θ-2θ x-ray diffraction pattern for a La0.7Sr0.3MnO3 / BaTiO3 film architecture grown by chemical solution deposition on SrTiO3 substrate.

An AFM image of the surface of a crystallized BTO film on a STO substrate is shown in figure 1 c). The surface structure indicates a very smooth surface. The value of the root mean square $R_{\text{rms}}$ is about 5 nm. Corresponding to the line scan shown in figure 1d) the average grain size is up to 100 nm. The BTO layer thickness was measured to be about 20 nm. The films were found to be crack-free, revealing the basis for a perfect isolating film character which is one of the most important requirements for multiferroic films.

3.3. Magnetic characterization of a LSMO layer

The temperature dependence of the magnetization of a single LSMO layer on STO was measured by SQUID in the temperature range from 5 to 350 K. To determine the ferromagnetic ordering temperature $T_C$ the magnetization curve was obtained by initially cooling the sample and then measuring its magnetic moment $m$ with increasing temperature under an applied external magnetic field of $\mu_0H=0.3$ T. The measurement of the Curie temperature $T_C$ is shown in figure 3 a). The value of $T_C$ has been derived by extrapolating the linear part of $m^2$ (T) to $m = 0$, resulting in $T_C = 360$ K. This value is insignificantly lower than the reported value for bulk LSMO ($T_C = 370$ K) [8, 9] which can be explained by the finite thickness of the film[10, 11]. By comparing the measured $T_C$ value with those of references on LSMO films, we conclude that the accurate La$_{0.7}$Sr$_{0.3}$MnO$_3$ phase was obtained.
3.4. Electrical characterisation

To realise a crack-free, fully isolating BTO film extremely thin BTO layers were prepared by ink plotting using a capillary of only 10 µm opening. Furthermore, a very slow heating rate of 60 K/h was realized during pyrolysis of the BTO films. The combination of the use of thin films and slow heating rates induces a careful oxidation reaction of the solvents. This leads to dense and crack-free BTO films with a film thickness of only 20 nm. To increase the film thickness the coating – annealing process was repeated several times. Electrical characterization of ferroelectric BTO films requires an electric conducting substrate. Therefore, a heterostructure was fabricated with LSMO acting as a ferromagnetic ground layer and simultaneously as an electric contact to the bottom electrode followed by the ferroelectric BTO layer on top. A liquid silver contact was deposited on top of the BTO layer, acting as the second electric contact. The schematic of such a multiferroic device is shown in figure 4. Polarization measurements were carried out at a heterostructure stack of LSMO / triple layer BTO / silver.
The polarization and corresponding displacement of the ions was recorded as a function of the applied voltage. When an electric field is applied along the BTO film a dipole alignment parallel to the electric field can be measured. Dipole alignment and corresponding elongation of the BTO crystal structure is reflected in hysteresis loops of polarization measurements [12]. The polarization hysteresis loop of a triple layer of BTO is shown in figure 5.

The remanent polarization (Pr) at room temperature is 0.015 µC/cm² and a saturation polarization of 0.025 µc/cm² was obtained for a 5V maximum applied voltage. These values clearly demonstrate the ferroelectric functionality of the BTO thin film. We obtained good reproducibility of these values of polarization when changing the measured multiferroic architecture. The decrease of the saturation polarization is due to a slight remaining leakage.
current. Leakage currents are likely attributed to a small BTO film thickness as reported in [13]. Yet, the switching processes still are detected.

4. Conclusions
In this study we demonstrated the preparation of a multiferroic device by complete chemical solution deposition route using environmentally friendly water based precursor solutions of LSMO and BTO. Requirements for the fabrication of such architecture are a very flat and homogeneous $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$ film as well as a crack free and non porous $\text{BaTiO}_3$ layer on top. The magnetic properties of the LSMO layer reveal a Curie temperature $T_C$ of 360 K and a saturation magnetization of about 560 emu/cm$^3$ for a 60 to 100 nm film thickness. Polarization measurements were carried out to demonstrate the switching processes of the BTO film when applying an electric field.

Acknowledgements
This work was funded by the European Union within the collaborative project (FP7): FP7-NMP-2007-SMALL-1 grant n°205854. We are thankful to K. Dörr and A. Herklotz for valuable discussions and K. Nenkov for SQUID measurements.

References